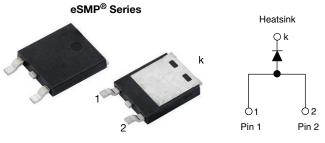
**Vishay Semiconductors** 

# Ultralow V<sub>F</sub> Ultrafast Rectifier, 8 A FRED Pt<sup>®</sup>



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SlimDPAK (TO-252AE)

# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	8 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	0.98 V				
t <sub>rr</sub> (typ.)	34 ns				
T <sub>J</sub> max.	175 °C				
Package	SlimDPAK (TO-252AE)				
Circuit configuration	Single				

### **FEATURES**

- Ultrafast recovery time, extremely low V<sub>F</sub> and soft recovery
- For PFC CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **TYPICAL APPLICATIONS**

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

## **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Base PN/-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 154 °C	8	^
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J$ = 25 °C, 10 ms sine pulse wave	130	
Operating junction and storage temperatures	TJ, T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	VF	I <sub>F</sub> = 8 A	8 A - 1.15					
	٧F	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	0.98	1.15			
Reverse leakage current	1-	$V_{R} = V_{R}$ rated	-	-	5			
neverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	100	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF		

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HALOGEN

FREE



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 5$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		45	-		
		$I_F = 1 A$ , $dI_F/dt = 1$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		34	-	ns	
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{RR} = 0.25 \text{ A}$		-	-	56		
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 500 A/μs V <sub>B</sub> = 400 V	-	75	-		
		T <sub>J</sub> = 125 °C		-	105	-		
Poole recovery current		T <sub>J</sub> = 25 °C		-	11.3	-		
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	16	-	A	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	420	-	20	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	1	-	840	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Thermal resistance, junction to mount	R <sub>thJM</sub>		-	-	2.2	°C/W		
Weight			-	0.20	-	g		
Marking device	Case style SlimDPAK (TO-252AE) 8EVL06							



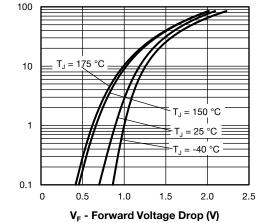


Fig. 1 - Typical Forward Voltage Drop Characteristics

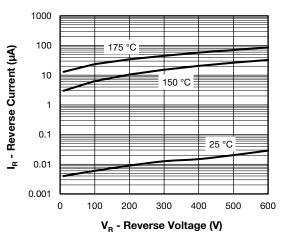


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



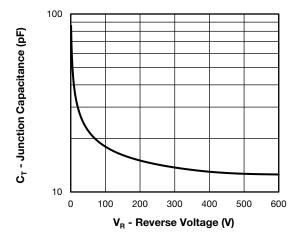


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

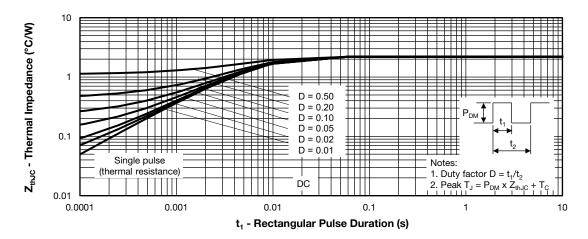
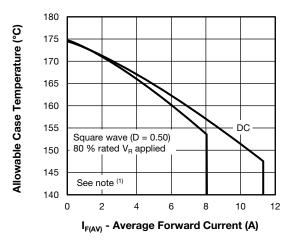
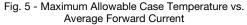


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V} \end{array}$ 

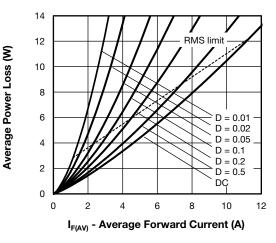


Fig. 6 - Forward Power Loss Characteristics

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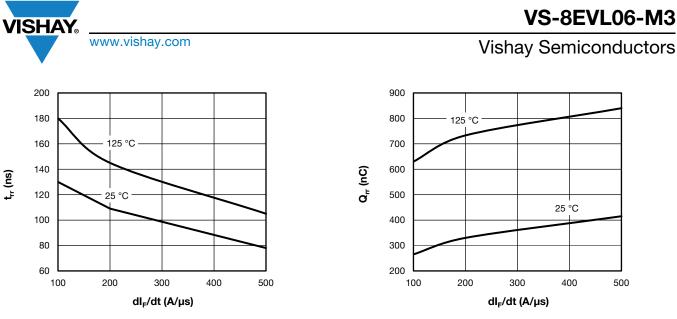


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



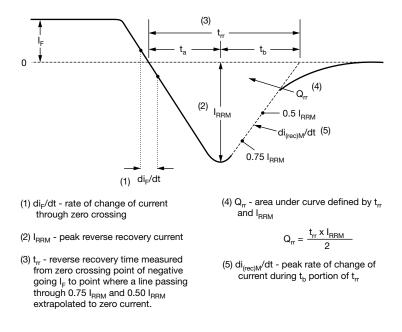


Fig. 9 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

Device code	VS-	8	E	v	L	06	-M3
		2	3	4	5	6	7
	1 2 3	Cur Circ	rent rati cuit conf	niconduo ng (8 = 8 iguratior	8 A)	oduct	
	4 - 5 -	V = Pro	single c SlimDP cess typ ultralow	AK	afast rec	tifier	
	6 · 7 ·	Env	rironmer	le (06 = ntal digit en-free,	:	complia	nt, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY PACKAGING DESCRIPTION							
VS-8EVL06-M3/I	0.20	I	4500	13"diameter plastic tape and reel				

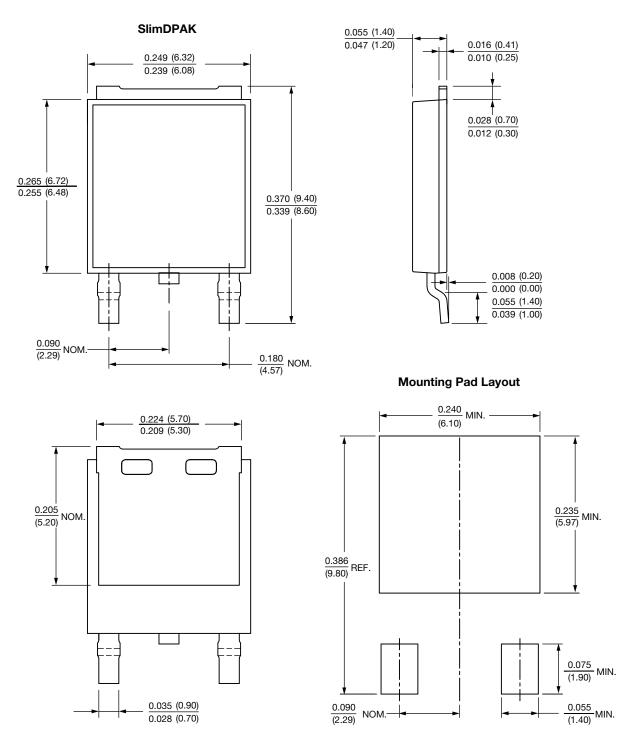
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96081				
Part marking information	www.vishay.com/doc?96085				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96738				





SlimDPAK

### **DIMENSIONS** in inches (millimeters)





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Revision: 01-Jan-2025

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